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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/681,482	10/08/2003	Ebrahim Abedifard	400.242US01	7469
27073	7590 04/15/2005		EXAMINER	
LEFFERT JAY & POLGLAZE, P.A.			HOANG, HUAN	
P.O. BOX 58 MINNEAPO	1009 LIS, MN 55458-1009		ART UNIT	PAPER NUMBER
			2827	
			DATE MAILED: 04/15/200	DATE MAILED: 04/15/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	10/681,482	ABEDIFARD ET AL.				
Office Action Summary	Examiner	Art Unit				
	Huan Hoang	2827				
The MAILING DATE of this communication appeared for Reply	pears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tim ly within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	rely filed s will be considered timely. the mailing date of this communication. O (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on						
2a) ☐ This action is FINAL. 2b) ☑ This	This action is FINAL. 2b)⊠ This action is non-final.					
·	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) ⊠ Claim(s) 1-24 is/are pending in the application 4a) Of the above claim(s) is/are withdra 5) ⊠ Claim(s) 12-15 and 22-24 is/are allowed. 6) ⊠ Claim(s) 1,5,7-11,16-18,20 and 21 is/are rejected to. 7) ⊠ Claim(s) 2-4,6 and 19 is/are objected to. 8) □ Claim(s) are subject to restriction and/or	wn from consideration.					
Application Papers	·					
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examine	cepted or b) objected to by the Edrawing(s) be held in abeyance. See tion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	ts have been received. ts have been received in Applicationity documents have been receive nu (PCT Rule 17.2(a)).	on No ed in this National Stage				
Attachment(s)		•				
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413)						
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 030504. 	Paper No(s)/Mail Da					

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DETAILED ACTION

Claim Rejections - 35 USC § 112

1. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

2. Claims 5 and 9-11 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The phrase "a first of the erase current" (claim 5, line 2) is confusing since there is only one erase current recited in claim 1.

Claims 5 and 9 recites the limitation "the second reference current level" in line 2.and line 12, respectively. There is insufficient antecedent basis for this limitation in the claim.

Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

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4. Claims 1, 5; 7, 9-11, 16 and 17 are rejected under 35 U.S.C. 102(e) as being anticipated by Hirano.

Hirano discloses a method of erasing a block of memory in a flash memory device and a flash memory device having all the steps and elements as recited in claims 1, 5, 7, 9-11, 16 and 17 as follows:

generating an erase pulse to the block of memory (column 7, line 17 and column 12, lines 30-33);

performing a current leakage check on each column (column 10, lines 8-13);

if a column is detected having a current leakage, determining an overerased memory cell (column 13, lines 6-9) in the column that has an erase current greater than a first reference current level (column 13, lines 24-27); and

applying a soft program pulse to the overerased memory cell (column 19, lines 1-4 and column 4, lines 29-31) until the erase current is less than the first reference current level.

Regarding claims 5 and 9, the second reference current level is considered to be the reference current (column 3, lines 24-27).

The erase current less than the first reference current level in the step of applying a soft program pulse to the overerased memory cell is inherent.

Claim Rejections - 35 USC § 103

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

6. Claims 8 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hirano in view of Joo.

Hirano discloses all the limitations of claims 8 and 18 except for the flash memory being a NAND-type flash memory. However, Joo discloses the use of a NAND-type flash memory for higher integration (column 1, lines 41-52). It would have been obvious to one having ordinary skill in the art at the time the invention was made to use a NAND-type flash memory in order to obtain higher integration.

7. Claims 20 and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hirano in view of Moarotta.

The only difference between claims 20 and 21 and Hirano is that Hirano does not disclose a processor and a state machine in the memory system. However, the processor and the state machine used in a memory system are well-known in the art to provide commands, instruction and control signals for the memory device and this is shown by Marotta (Fig. 1). It would have been obvious to one having ordinary skill in the art to use a processor and a state machine in a memory system in order to provide provide commands, instruction and control signals for a memory device.

Allowable Subject Matter

8. Claims 12-15 and 22-24 are allowed.

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9. Claims 2-4, 6 and 19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

The prior art fails to disclose the following limitations:

prior to performing the current leakage check, applying additional erase pulses to memory cells that have an erase current less than a second reference current until the erase current is at least equivalent to the second reference current level.

wherein the block of memory further includes a plurality of wordlines coupling rows of memory cells and the method further including applying a positive voltage to a selected wordline of the plurality of wordlines and a negative voltage to unselected wordlines.

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Huan Hoang whose telephone number is (571) 272-1779. The examiner can normally be reached on Mon-Fri 8:30AM-5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Hoai Ho can be reached on (571) 272-1777. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

> Huan Hoang Primary Examiner Art Unit 2827

HH4/13/05.